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Ab Initio Study on the Vibrational and Electronic Properties of Radiation-Induced Defects in Potassium Bromide

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Abstract: The vibrational and electronic properties of several basic radiation defects in potassium bromide are computed at the quantum mechanical level using a periodic supercell approach based on hybrid functionals, an all-electron Gaussian-type basis set, and the CRYSTAL computer code. The exciton energy in alkali halides is sufficient to create lattice defects, such as F–H Frenkel defect pairs, resulting in a relatively high concentration of single defects and their complexes. Here, we consider eight defects: the electronic F^+ - and F-centers (bromine vacancy without and with trapped electrons) and their dimers; hole H-center (neutral bromine atom forming the dumbbell ion with a regular Br^- ion.); V_K -center (Br_2^- molecular ion consisting of a hole and two regular ions); and two complex Br_3^- defects, combinations of several simple defects. The local geometry and the charge- and spin-density distributions of all defects are analyzed. Every defect shows its characteristic features in Raman spectra, and their comparison with available experimental data is discussed.

Keywords: alkali halides; KBr; interstitial defects; F-type centers; hole centers; electronic structure; vibrational properties; Raman spectroscopy



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1. Introduction

KBr crystals are used as carriers for samples in IR measurements [1] and as models in studies of radiation-induced processes [2–6]. Moreover, when KBr is doped with various impurities, it exhibits excellent radiation storage properties and has, therefore, been proposed as an X-ray and UV photostimulable storage phosphor [7], a thermoluminescent dosimeter [8], or a neutron storage phosphor [9].

As is well known, the irradiation of alkali halides leads to the formation of self-trapped holes (V_K -centers) and primary Frenkel defects: pairs of the F-center (halide vacancy with trapped electrons) and the H-center (interstitial halide atom forming the dumbbell (Hal) $_2^-$ configuration with a regular anion) [10–12]. The basic properties of these defects have been studied through optical and vibrational spectroscopy (Table 1).

The thermal stability of primary radiation defects in KBr has been discussed more than once [13–15]. Here, it is important to emphasize that secondary reactions and all changes that occur with points defects, of which there can be several types at the same time, are determined by the least stable defect, which begins to migrate and thus initiates the entire chain of secondary reactions. Furthermore, the release of a mobile defect from traps also often occurs, for example, in the case of H-centers captured on homologous cationic impurities [16] or during the thermal decomposition of a complex hole center (V_2 -centers, which are (Hal_3^-)) into its simple components (V_k and H) [17,18].

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| Defect | Optical Absorption (eV) | Local Vibrational Modes (cm^{-1}) | |
|----------------|----------------------------|---------------------------------------|--|
| F | 1.97 [2], 2.0 [3] | 110, 121 [3]; 175 [4] | |
| Н | 3.2 [2] | 182, 209 [5] | |
| V_K | 3.2 [2] | 144 [5] | |
| $V_2 (Br_2^-)$ | 4.7 [2], 4.5 [6], 4.6 [19] | 175 [4,6] | |

Table 1. The basic optical and vibrational properties of the defects in KBr crystals.

We would like to note that the problems considered in this work are especially important in the following cases. The first is when there are several overlapping optical absorption bands, making the accurate identification of point defects difficult. The second is when the sample receives such a large dose of radiation that the concentration of the created radiation defects is so high that it leads to the saturation of optical absorption and, accordingly, the impossibility of measuring the corresponding spectra. Defect-induced Raman modes were successfully identified in oriented single crystals of yttria-doped CeO_2 , induced by the defect space, including an O^{2-} vacancy [20]. Another example is the observation of defect-induced Raman spectra in cubic zirconia [21], which also implies oxygen vacancies. As for materials irradiated by radiation, it is essential to mention Ar^+ ion-irradiated MoS_2 [22], Xe ion-irradiated $MgAl_2O_4$ single crystals [23], neutron-irradiated graphite [24], transparent polycrystalline chemical vapor deposition (CVD) diamond films [25], 6H-SiC single crystals [26], $Gd_3Ga_5O_{12}$ [27], and many others. Theoretically, these issues were recently considered for anion vacancy-containing Al_2O_3 [28], as well as $BaTiO_3$ and $SrTiO_3$ [29].

In alkali halides, Raman spectroscopy measurements are widely used for the identification of the F-centers, but much less information is available on the hole centers. In this paper, using the first principles of quantum chemical methods, we study the properties of basic radiation defects and their complexes in potassium bromide crystals, providing insight into their structural, electronic, and vibrational features.

2. Computational Methods

Calculations were performed using the B3LYP global hybrid functional [30,31], as implemented in the CRYSTAL17 computer code [32]. An all-electron Gaussian-type basis set of double-zeta valence with polarization quality (pob-DZVP-rev2) was used for both K and Br, following the publication by Oliveira et al. [33]. The truncation of the Coulomb and exchange infinite lattice series is controlled by five thresholds for T_i (see CRYSTAL manual, Ref. [34], for more details), which were set to 7 (T_1 – T_4) and 14 (T_5). The convergence thresholds for the energy in the self-consistent field (SCF) procedure were set to T_5 0 and T_5 1 and T_5 2. The convergence thresholds for the structural and frequency calculations, respectively. Geometry optimization was performed for pristine crystal and every defect prior to the frequency calculations. The calculations were performed on a CINECA MARCONI supercomputer A3 partition with Xeon 8160 (SkyLake) processors, using up to 960 cores for a single calculation.

Two periodic supercell models of extended primitive cells were used: a 250-atom supercell (S_{250}) for bromine vacancy defects, and a 128-atom supercell S_{128} for hole-type defects. The sizes of the selected supercells proved to be sufficient for a proper description of the point defects in alkali halides [35]. Due to the higher symmetry of the F-center defects, it was possible to obtain a solution for the larger model using nearly the same number of resources as for hole-type defects. Overall, the sizes of the basis set (number of AOs) were about 3264 in S_{128} and 6343 in S_{250} . The reciprocal space was sampled using a regular sub-lattice with a shrinking factor of 4 for S_{128} and 2 for S_{250} ; this corresponds to a number of k-points ranging from 4 to 18, according to the point symmetry of the defective system. The F^+ , V_K , and Br_3^- defects were calculated with an applied neutralizing background charge. The structural files and details of the vibrational calculations can be found in the Supplementary Materials.

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The frequencies at the Γ point were obtained within the harmonic approximation by diagonalizing the mass-weighted Hessian matrix, W, whose elements are defined as [36–39]

$$W_{\alpha i,\beta j}^{\Gamma} = \frac{H_{\alpha i,\beta j}^{\mathbf{0}}}{\sqrt{M_{\alpha} M_{\beta}}} \quad \text{with} \quad H_{\alpha i,\beta j}^{\mathbf{0}} = \left(\frac{\partial^{2} E}{\partial u_{\alpha i}^{\mathbf{0}} \partial u_{\beta j}^{\mathbf{0}}}\right), \tag{1}$$

where M_{α} and M_{β} are the masses of atoms associated with the i and j atomic coordinates. Once the Hessian matrix, $\mathcal{H}_{\alpha i,\beta j}$, has been calculated, the frequency shifts due to isotopic substitutions can be easily calculated at no additional computational cost by changing the masses in Equation (1). The energy-first derivatives with respect to the atomic positions are calculated analytically for all the coordinates, whereas the second derivatives are calculated numerically using a single displacement along each coordinate.

The relative Raman intensities of the peaks are computed analytically by employing the scheme illustrated in [40,41]. Both schemes are based on the solutions of first- and second-order coupled-perturbed Hartree–Fock/Kohn–Sham (CPHF/KS) equations [42–45]. The Raman spectrum is then computed by considering the transverse optical (TO) modes and adopting a pseudo-Voigt functional form: a linear combination of a Lorentzian and a Gaussian curve with an FWHM of 8 cm⁻¹.

3. Results and Discussion

3.1. Perfect KBr

Perfect KBr is an alkali halide with a face-centered cubic lattice belonging to the $Fm\overline{3}m$ (No.225) space group. The calculated lattice parameter (a = 6.606 Å vs. exp. 6.585 Å [46]), providing K-Br 3.303 Å, and the band gap (7.37 eV vs. exp. 7.55 eV [47]) are in good agreement with the experimental data. For a clearer understanding of the defect-induced vibrational modes, we also calculated the phonon density of states (Figure 1), spanning from 16 to 162 cm⁻¹ with a maximum at 122 cm⁻¹. Experimentally, the LO phonon maximum was observed at 164 cm⁻¹ [4]. The Raman spectra of pristine KBr were silent; however, the symmetry reduction due to the presence of defects in the supercell model may have resulted in modes not directly associated with a defect. Obviously, all modes higher than 162 cm⁻¹ can be easily attributed to the defect, but for those falling in the PDOS region, careful mode analysis with the help of isotopic substitutions was performed.

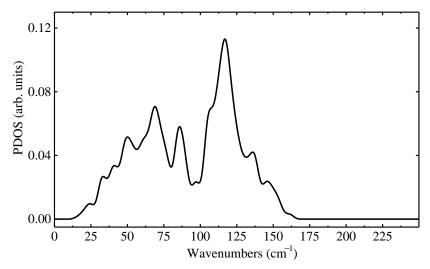


Figure 1. Calculated total phonon density of states of KBr crystal. PDOS extends from 16 to 162 cm⁻¹. *3.2. Hole-Type Defects*

The electron-hole mechanism is considered one of the main processes leading to the creation of Frenkel pairs (F-center + interstitial) in alkali halides [12,48–50]. Holes are trapped at the anion sites, creating neutral halogen atoms that are reactive and can move

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through the lattice, forming the Br_2^- dumbbell with regular Br^- ions. Here, we discuss four types of defects: the V_K -center, where a single hole is trapped at two anion sites, resulting in a Br_2^- molecular ion lying along the <110> direction; the H-center, representing a neutral bromine interstitial trapped at the occupied anion site, also resulting in a Br_2^- molecular ion lying along the <110> direction, but in this case, it occupies a single anion site; the Br_3^- <110> defect, a combination of the latter two, involving two holes and one interstitial halogen ion; and the Br_3^- <100> defect—a bromine interstitial and a hole trapped at the cation vacancy site. Their electronic structures are shown in Figure 2. The calculated properties of all defects are presented in Table 2. For comparison purposes, we also calculated the free Br_2 molecule and Br_3^- molecular ion.

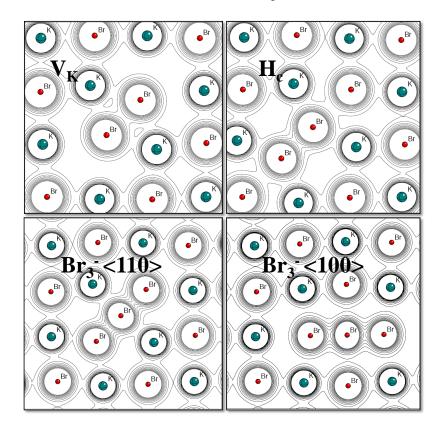


Figure 2. Total electron density maps of hole-type defects. View along the (100) plane. The isolines range from 0 to 0.1 a.u with a step of 0.01 a.u.

Table 2. Calculated structural and localized vibrational modes (LVMs) of hole defects in KBr crystal and free Br₂, Br₂⁻, and Br₃⁻ species. Distance between Br atoms (d_{Br-Br} , Å) involved in defect formation, their charges (q_{Br} , e), and magnetic moments (μ_{Br}) resulting from Mulliken analysis. LVMs (in cm⁻¹) were assigned based on the highest mode shifts for ⁷⁹Br \rightarrow ⁸¹Br isotopic substitution.

| Defect | d_{Br-Br} | q_{Br} | μ_{Br} | LVM (cm ⁻¹) |
|--------------------------|-------------|-------------------|-------------|-------------------------|
| V_K -center | 3.04 | -0.43/-0.43 | 0.495/0.495 | 90, 121, 165, 169, 179 |
| H-center | 2.83 | -0.46/-0.48 | 0.462/0.441 | 181, 190, 204, 207 |
| $Br_3^- < 110 >$ | 2.59/2.65 | -0.36/-0.10/-0.43 | - | 95, 170, 173, 206, 227 |
| $Br_3^- < 100 >$ | 2.66/2.66 | -0.46/+0.05/-0.45 | - | 68, 116, 141, 149, 186 |
| Br ₂ molecule | 2.38 | 0.0/0.0 | - | 302 |
| Br_2^- mol. ion | 2.97 | -0.5/-0.5 | 0.5/0.5 | 140 |
| Br_3^2 mol. ion | 2.65/2.66 | -0.45/-0.10/-0.45 | - | 84, 150, 203 |

The calculated vibrational frequency of free molecular bromine is 302 cm^{-1} , which is in good agreement with both 306 cm^{-1} for liquid Br₂ [51] and 301 cm^{-1} [52] for crystal. All

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hole-type defects act as shallow acceptors, as seen in Figure 3. The V_K -center reveals an unoccupied level in the gap just 1.09 eV above the top of the valence band. The H-center shows an occupied spin-up level in the gap, whereas the spin-down unoccupied level lies 2.75 eV above the valence band maximum. Br_3^- is a closed-shell defect, and its occupied states lie within the valence bands, with the unoccupied levels at 2.27-2.33 eV above the valence band maximum. The optical absorption of the hole centers arises due to electron transitions between local levels in the valence band and unoccupied levels in the gap (Figure 3). The V_K -center occupies an interstitial position, where two bromine ions left their regular sites, leaving behind several K ions low-coordinated and located very close to two K ions. The V_K -center is quite similar to the free Br_2^- ion in terms of both the bond length and spin localization. As we can see from the mode analysis, the three highest vibrational modes (Figure 4 and Table 2) are associated with symmetric and anti-symmetric stretching of these two K ions. The peak at around 145 cm⁻¹ is composed of multiple modes associated with the motion of low-coordinated K cations, which is in good agreement with the observed value of 144 cm^{-1} [5]. The most intense peak in the spectra, as expected, is due to Br-Br stretching at 121 cm $^{-1}$.

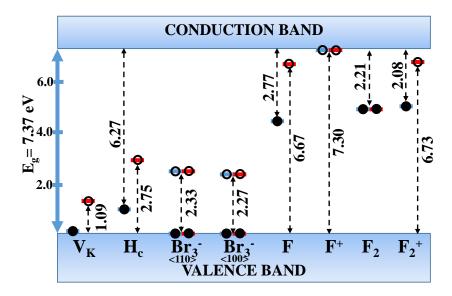


Figure 3. Schematic representation of defect levels in the band gap. All indicated levels arise from atoms (in the case of bromine molecular ions) or orbitals (in the case of F-centers) involved in defect formation. Filled and empty circles correspond to occupied and unoccupied levels. Blue and red dashes correspond to spin-up and spin-down states, respectively.

We expected the next defect, the H-center, to exhibit similar behavior to the previous defect, but as we can see in Table 2, they are very different. The bond length is shorter than that in free Br_2^- , the charge and spin densities are slightly asymmetric, and the induced vibrational modes fall between molecular and ionized Br_2 . Here, two atoms are occupying a single anion site, possibly leading to bond shortening due to the close-packed surroundings. The two intense peaks in the calculated spectra (Figure 4) are composed of several modes: the peak at around 204 cm⁻¹ contains asymmetric and symmetric K-Br-K stretching (K ions that are seen in Figure 2 around the H_c defect), and the peak at 181 cm⁻¹ is from Br-Br stretching modes. The other peak at 114 cm⁻¹ is due to the K-Br stretching of potassium ions that have a strong interaction with both bromine atoms involved in defect formation.

The last hole-type defect is Br_3^- , which can appear in two very different forms. A linear free Br_3^- molecular ion has three vibrational modes: bending, symmetric stretching, and asymmetric stretching (in ascending order). All of them also appear in crystal defects. The first is a combination of two previous defects: V_K and H_c . In this case, the Br_3^- molecular ion is oriented in the <110> direction, occupying two anion sites. As expected, the highest mode at 227 cm⁻¹ belongs to the asymmetric stretching of Br-Br-Br. The mode at 206 cm⁻¹

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is similar to the H_c mode at 114 cm⁻¹, but in this case, such K-Br-K stretching does not give rise to the peak in the Raman spectrum. The most intense peak at around 172 cm $^{-1}$ is composed of two modes: Br-Br-Br symmetric stretching and K-Br-K bending. The mode at 95 cm⁻¹ is Br-Br-Br bending, but it also does not give rise to the Raman peak. The second Br_{3}^{-} defect, oriented in the <100> direction, occupies two anion sites and one vacant cation site. Despite the electronic structures of both defects being very similar (see Table 2), the modes and resulting Raman spectra are very different. The asymmetric Br-Br-Br stretching mode is now at 186 cm⁻¹ with almost zero intensity. As in the previous case, the most intense peak is due to Br-Br-Br symmetric stretching at around 149 cm⁻¹. The bending mode is found at 116 cm⁻¹, while a series of low-intensity peaks at 45–65 cm⁻¹ is associated with the rotational motion of molecular ions. From the spectra, we can see that only a few modes produce high intensity, likely due to the specific surroundings of the cation vacancy. Comparing the two spectra, we can see that $Br_3^- < 110 >$ has Raman peaks associated with modes that are not listed in Table 2 and are thus not affected by the isotopic substitution of bromine ions. These are mostly associated with potassium ion vibrations around the defect. Since the defect is positively charged with respect to the regular lattice, the surrounding ions experience a less attractive force. In the case of Br_3^- <100>, there is also potassium vacancy involved (negatively charged with respect to the regular lattice), so the defect complex might be considered a net-zero charge.

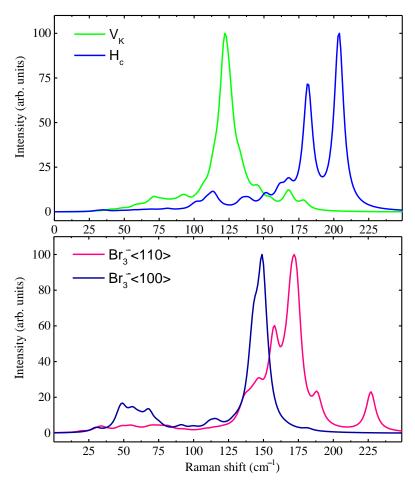


Figure 4. Simulated Raman spectra of four hole-type defects. All intensities were normalized to 100 arb. units.

Our findings are in good agreement with the experimentally observed values of 182 and 209 cm⁻¹ [4,5], which can be attributed both to H_c and $Br_3^- <110>$. Samples with excess bromine in experiments show multiple peaks above $200 \, \mathrm{cm}^{-1}$, which are associated with molecular bromine and large molecular ions, such as Br_5^- . The experimental peak

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at around 125 cm^{-1} can be easily confused with the V_K -center, but the peak at the same position is also produced by the F-center, which is way more stable and more likely to be present in the sample [4].

3.3. Vacancy Defects

In contrast to hole-type defects, vacancy defects do not produce new bonds in the crystal so they are more challenging to identify with vibrational spectroscopy methods. Usually, F-centers can be explicitly studied using optical methods, but at high doses of irradiation when samples become opaque, such methods are no longer useful. The experimentally observed optical absorption region for the single F-center is around $2\,\mathrm{eV}$ (see Table 1). The filled defect level for the F-center, as shown in Figure 3, is located slightly below the bottom of the conduction band (CBM), in agreement with the mentioned experiments. Obviously, this is not the case for empty vacancies (F⁺), which produce additional levels very close to the CBM.

We start the description of the vibrational properties of vacancy defects with a simple example, which preserves the full symmetry of the crystal-F $^+$ defect. All peaks seen in Figure 5 are formed by modes that involve six K cations around the vacancy site. The most intense peak at 171 cm $^{-1}$ is formed by the single-degenerate A_{1g} mode; all other modes (see Table 3) are triple-degenerate F_{2g} modes. The modes below 100 cm^{-1} are almost unaffected by isotopic substitution, but an analysis of the modes reveals that they are mostly E_g modes, associated with Br-K stretching around the vacancy site. In the experiment [4]. the mode at 175 cm^{-1} was assigned to the anion vacancy defect since its intensity drastically decreased in samples with excess bromine.

Table 3. Calculated structural and localized vibrational modes (LVMs) of vacancy defects in KBr crystal. Distances from a vacancy site to the closest K atoms (d_{V-K} , Å), K-Br bond length intervals for K atoms around the vacancy (d_{K-Br} , Å), net charge (|q| in e), and magnetic moment (μ in μ_B) localized in the vacancy resulting from Mulliken analysis. LVMs were assigned based on the highest modes shifts for 39 K \rightarrow 42 K isotopic substitution of atoms around the vacancy site. For F₂, d_{V-K} distances correspond to 5- and 4-coordinated K atoms.

| Defect | d_{V-K} | d_{K-Br} | q | μ | LVM (cm ⁻¹) |
|--------------------|-------------|------------|--------|-------|------------------------------|
| F | 3.03 | 3.28-3.46 | -0.816 | 0.948 | 108, 124, 137, 149, 156, 167 |
| F^+ | 3.57 | 3.13-3.25 | 0.0 | 0.0 | 125–135, 145, 154, 171 |
| F_2 | 2.87 / 2.53 | 3.30-3.97 | -1.598 | 0.0 | 127, 160, 169, 187 |
| $\overline{F_2^+}$ | 3.53 / 3.32 | 3.15-3.35 | -0.830 | 1.028 | 153, 158, 188 |

Taking a closer look at the calculated F-center modes, we find out that they are very similar to the F^+ ones, with two exceptions: first, in the neutral F defect, the single-degenerate mode had a negative value, which required the scanning of the geometry along the selected mode (SCANMODE option in Ref. [34]) to obtain the ground-state solution. And second, Raman intensities for the same modes turned out to be different. Due to symmetry reduction, the triple-degenerate F_{2g} modes split into $E+A_1$ modes, with a difference that did not exceed 1 cm $^{-1}$. Despite having similar modes, differences in polarizability played a crucial role in distinguishing the two defects in Raman spectra. In the presence of the F^+ defect, the peak at 175 cm $^{-1}$ dominated the spectra [4], but when the sample contained only neutral defects, a peak at 156 cm $^{-1}$ was observed without overlapping with others. In general, the obtained results for the single vacancy defects are in good agreement with the experimental data in terms of both the positions of mode and their relative intensities.

We also studied anion divacancies in two charge states: neutral (F_2) and singly charged (F_2^+) . These defects were not observed in previously mentioned experimental papers, but they can be created under stress and irradiation [53]. Mode analysis revealed that for both defects, the most intense peak at 188 cm^{-1} was due to 4-coordinated potassium ion motion.

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For charged divacancy, all other modes exhibited relatively low intensities, while in the neutral case, an additional three modes with considerable intensities appeared. Similar to single vacancies, all of them involved K cations around the vacancy sites.

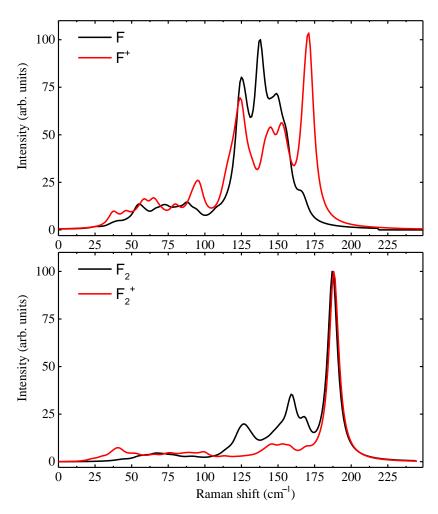


Figure 5. Simulated Raman spectra of F-type defects. All intensities were normalized to 100 arb. units.

4. Conclusions

We have presented the vibrational modes and Raman spectra, which are in good agreement with the experimental data, as well as the local geometry and the charge and spin (when applied) distributions, for radiation-induced defects in potassium bromide. We investigated a series of hole-type defects, resulting in the formation of molecular ions within the defect sites. Our results showed a clear distinction between two very similar Br_3^- defects that occupied different sites in the crystal, where Br_3^- <110> showed several additional peaks between 125 cm $^{-1}$ and 225 cm $^{-1}$ compared to the <100> configuration. It was also demonstrated that the charges of the single (F-type) and dimer (F₂-type) electron centers considerably affected their Raman spectra, which could be used for defect identification. The obtained results could be used for the identification of radiation defects under huge radiation fluences and extended to the defect analysis in similar halide compounds.

Supplementary Materials: The following are available online at https://www.mdpi.com/article/10.3390/cryst14020161/s1, containing structural files and raw calculation outputs.

Author Contributions: Conceptualization, A.D., A.I.P. and E.A.K.; investigation and formal analysis, A.P., V.P., A.D., E.A.K. and A.I.P.; methodology, resources, data curation, and writing—original draft preparation, A.P. and V.P.; writing—review and editing, A.P., V.P., A.D., E.A.K. and A.I.P.;

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